

#### **NPN Silicon RF Transistor\***

- For ESD protected high gain low noise amplifier
- Excellent ESD performance typical value 1000 V (HBM)
- Outstanding G<sub>ms</sub> = 20 dB
   Noise Figure F = 0.9 dB
- SIEGET ® 45 Line
- Pb-free (ROHS compliant) package<sup>1)</sup>
- Qualified according AEC Q101
- \* Short term description





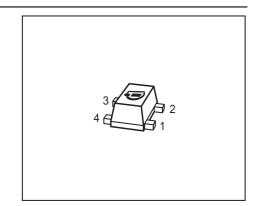
## ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration Pack						Package
BFP540FESD	AUs	1=B	2=E	3=C	4=E	-	-	TSFP-4

### **Maximum Ratings**

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$		V
<i>T</i> <sub>A</sub> > 0°C		4.5	
$T_A \le 0$ °C		4	
Collector-emitter voltage	V <sub>CES</sub>	10	
Collector-base voltage	$V_{\mathrm{CBO}}$	10	
Emitter-base voltage	V <sub>EBO</sub>	1	
Collector current	I <sub>C</sub>	80	mA
Base current	I <sub>B</sub>	8	
Total power dissipation <sup>2)</sup>	P <sub>tot</sub>	250	mW
<i>T</i> <sub>S</sub> ≤ 80 °C			
Junction temperature	$ T_{i} $	150	°C
Ambient temperature	$ T_{A} $	-65 150	
Storage temperature	T <sub>stg</sub>	-65 150	

<sup>&</sup>lt;sup>1</sup>Pb-containing package may be available upon special request



 $<sup>^2</sup>T_{
m S}$  is measured on the collector lead at the soldering point to the pcb





#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	R <sub>thJS</sub>	≤ 280	K/W

# **Electrical Characteristics** at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	4.5	5	-	V
$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$					
Collector-emitter cutoff current	I <sub>CES</sub>	-	-	10	μA
$V_{CE} = 10 \text{ V}, V_{BE} = 0$					
Collector-base cutoff current	I <sub>CBO</sub>	-	-	100	nA
$V_{\rm CB} = 5 \text{ V}, I_{\rm E} = 0$					
Emitter-base cutoff current	I <sub>EBO</sub>	-	-	10	μΑ
$V_{\rm EB} = 0.5  \rm V,  \it I_{\rm C} = 0$					
DC current gain	h <sub>FE</sub>	50	110	170	-
$I_{\rm C}$ = 20 mA, $V_{\rm CE}$ = 3.5 V, pulse measured					

 $<sup>^{1}\</sup>mbox{For calculation of}\,R_{\mbox{\scriptsize thJA}}$  please refer to Application Note Thermal Resistance





**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics (verified by random sampling	g)		,	ı	
Transition frequency	$f_{T}$	21	30	-	GHz
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 4 V, $f$ = 1 GHz					
Collector-base capacitance	C <sub>cb</sub>	-	0.16	0.26	pF
$V_{\text{CB}} = 2 \text{ V}, f = 1 \text{ MHz}, V_{\text{BE}} = 0 ,$					
emitter grounded					
Collector emitter capacitance	C <sub>ce</sub>	-	0.4	-	
$V_{CE} = 2 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$ ,					
base grounded					
Emitter-base capacitance	$C_{eb}$	-	0.55	-	
$V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{\text{CB}} = 0$ ,					
collector grounded					
Noise figure	F				dB
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 2 V, $f$ = 1.8 GHz, $Z_{\rm S}$ = $Z_{\rm Sopt}$		-	0.9	1.4	
$I_{\rm C} = 5 \text{ mA}, \ V_{\rm CE} = 2 \text{ V}, \ f = 3 \text{ GHz}, \ Z_{\rm S} = Z_{\rm Sopt}$		-	1.3	-	
Power gain, maximum stable <sup>1)</sup>	G <sub>ms</sub>	-	20	-	dB
$I_{\rm C}$ = 20 mA, $V_{\rm CE}$ = 2 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
$Z_{L} = Z_{Lopt}$ , $f = 1.8 \text{ GHz}$					
Power gain, maximum available <sup>1)</sup>	G <sub>ma</sub>	-	14.5	-	dB
$I_{\rm C}$ = 20 mA, $V_{\rm CE}$ = 2 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
$Z_{L} = Z_{Lopt}, f = 3 \text{ GHz}$					
Transducer gain	$ S_{21e} ^2$				dB
$I_{\rm C}$ = 20 mA, $V_{\rm CE}$ = 2 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ , $f$ = 1.8GHz		15.5	18	-	
$I_{\rm C}$ = 20 mA, $V_{\rm CE}$ = 2 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ , $f$ = 3GHz		_	13	-	
Third order intercept point at output <sup>2)</sup>	IP <sub>3</sub>	-	24.5	-	dBn
$V_{\text{CE}}$ = 2 V, $I_{\text{C}}$ = 20 mA, $Z_{\text{S}}$ = $Z_{\text{L}}$ = 50 $\Omega$ , $f$ = 1.8GHz					
1dB Compression point at output	P <sub>-1dB</sub>	-	11	-	
$I_{\rm C}$ = 20 mA, $V_{\rm CE}$ = 2 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ , $f$ = 1.8GHz					

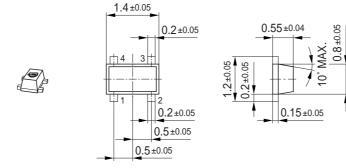
 $<sup>{}^{1}</sup>G_{ma} = |S_{21e} / S_{12e}| (k-(k^{2}-1)^{1/2}), G_{ms} = |S_{21e} / S_{12e}|$ 

<sup>&</sup>lt;sup>2</sup>IP3 value depends on termination of all intermodulation frequency components.

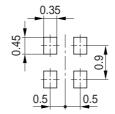
Termination used for this measurement is 50  $\Omega$  from 0.1 MHz to 6 GHz



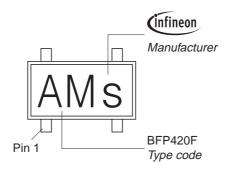
### Package Outline



#### Foot Print

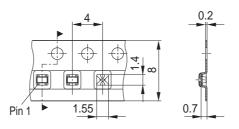


### Marking Layout (Example)



### Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





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